



### DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

## **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(on)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C
30V	16mΩ @ V <sub>GS</sub> = 10V	9.8A
	22mΩ @ V <sub>GS</sub> = 4.5V	8.4A

## Description

This MOSFET has been designed to minimize the on-state resistance  $(R_{DS(on)})$  and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

# Applications

- Backlighting
- Power Management Functions
- DC-DC Converters

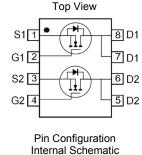
## **Features and Benefits**

- 100% avalanche rated part
- Low R<sub>DS(on)</sub> minimizes conduction losses
- Low Q<sub>g</sub> minimizes switching losses
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 standards for High Reliability
- PPAP Capable (Note 4)

## **Mechanical Data**

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208<sup>3</sup>
- Weight: 0.076 grams (approximate)





 $G_1 \longrightarrow G_2 \longrightarrow G_2$ 



Part Number	Compliance	Case	Packaging
DMG4800LSD-13	Standard	SO-8	2,500 / Tape & Reel
DMG4800LSDQ-13	Automotive	SO-8	2,500 / Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

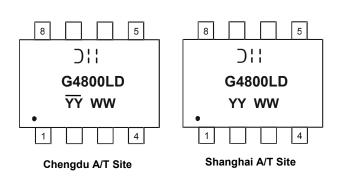
 See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q10x and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product\_compliance\_definitions/.

For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



)'' = Manufacturer's Marking
G4800LD = Product Type Marking Code
YYWW = Date Code Marking
YY or YY = Year (ex: 14 = 2014)
WW = Week (01 - 53)
YY = Date Code Marking for SAT (Shanghai Assembly/ Test site)
YY = Date Code Marking for CAT (Chengdu Assembly/ Test site)



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V <sub>DSS</sub>	30	V
Gate-Source Voltage			V <sub>GSS</sub>	±25	V
Continuous Drain Current (Note 7) V <sub>GS</sub> = 10V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	7.5 6.0	A
	t<10s	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	9.8 7.7	A
Continuous Drain Current (Note 7) V <sub>GS</sub> = 4.5V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	6.4 5.0	A
	t<10s	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	Ι <sub>D</sub>	8.4 6.6	A
Maximum Continuous Body Diode Forward Current (Note 7)			ls	2	A
Pulsed Drain Current (10µs pulse, duty cycle = 1%)			I <sub>DM</sub>	42	A
Avalanche Current (Notes 8 & 9) L = 0.1mH			I <sub>AR</sub>	17	A
Repetitive Avalanche Energy (Notes 8 & 9) L = 0.1mH			E <sub>AR</sub>	14	mJ

# **Thermal Characteristics**

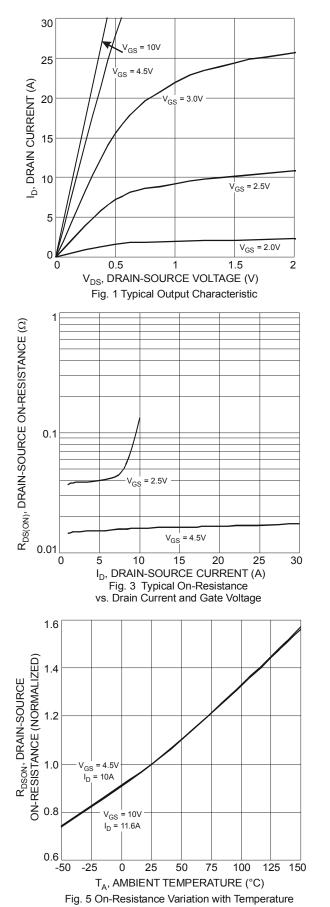
Characteristic		Symbol	Value	Units	
Total Power Dissipation (Note 6)		PD	1.17	W	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	D	107	°C/W	
memai Resistance, Junction to Ambient (Note 6)	t<10s	R <sub>θJA</sub>	61		
Total Power Dissipation (Note 7)		PD	1.5	W	
Thermal Resistance, Junction to Ambient (Note 7)	Steady State	D	83	°C/W	
memorial Resistance, Junction to Ambient (Note 7)	t<10s	R <sub>θJA</sub>	49		
Thermal Resistance, Junction to Case	R <sub>θJC</sub>	14.5			
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to 150	°C	

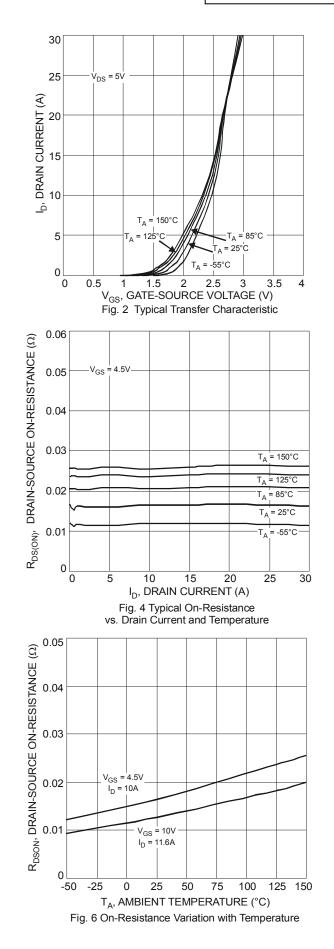
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 10)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	30	-		V	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250µA	
Zero Gate Voltage Drain Current TJ = +25°C	I <sub>DSS</sub>	—	—	1.0	μA	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	IGSS	—	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 10)		_	_	_		_	
Gate Threshold Voltage	V <sub>GS(th)</sub>	0.8	—	1.6	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance	Б	_	12 16	16 22	mΩ	V <sub>GS</sub> = 10V, I <sub>D</sub> = 9A	
	R <sub>DS(on)</sub>					V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 7A	
Forward Transfer Admittance	Y <sub>fs</sub>	—	8	_	S	V <sub>DS</sub> = 10V, I <sub>D</sub> = 9A	
Diode Forward Voltage	V <sub>SD</sub>	—	0.72	0.94	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = 1A	
DYNAMIC CHARACTERISTICS (Note 11)							
Input Capacitance	C <sub>iss</sub>		798		pF		
Output Capacitance	C <sub>oss</sub>		128		pF	V <sub>DS</sub> = 10V, V <sub>GS</sub> = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>		122		pF	-1 = 1.0 WHz	
Gate Resistance	R <sub>g</sub>		1.37		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg		8.56		nC	V <sub>GS</sub> = 5V, V <sub>DS</sub> = 15V, 	
Gate-Source Charge	Q <sub>gs</sub>	—	1.8	—	nC		
Gate-Drain Charge	Q <sub>gd</sub>	_	2.5	_	nC		
Turn-On Delay Time	t <sub>D(on)</sub>		5.03		ns	V <sub>DD</sub> = 15V, V <sub>GEN</sub> = 10V, R <sub>L</sub> = 15Ω, R <sub>G</sub> = 6Ω, I <sub>D</sub> = 1A	
Turn-On Rise Time	tr	_	4.50	_	ns		
Turn-Off Delay Time	t <sub>D(off)</sub>	—	26.33	—	ns		
Turn-Off Fall Time	t <sub>f</sub>	_	8.55	_	ns		

6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
7. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
8. I<sub>AR</sub> and E<sub>AR</sub> rating are based on low frequency and duty cycles to keep T<sub>J</sub> = +25°C.
9. Applicable to products manufactured with Data Code "1146" (Nov, 2011) and newer.
10. Short duration pulse test used to minimize self-heating effect.
11. Guaranteed by design. Not subject to product testing. Notes:







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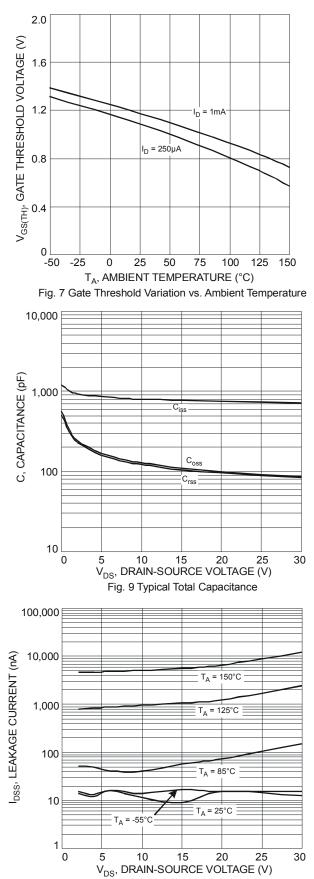
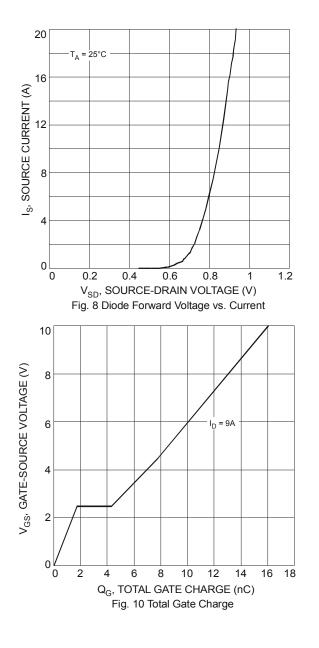
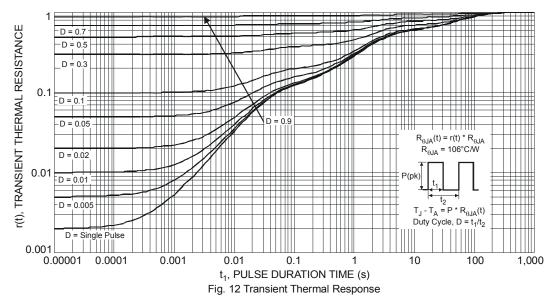


Fig. 11 Typical Leakage Current vs. Drain-Source Voltage

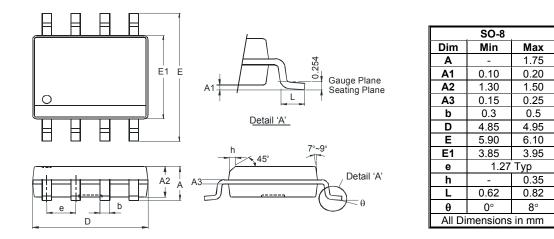






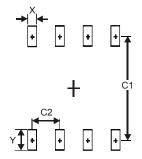
# Package Outline Dimensions

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



# Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Х	0.60
Y	1.55
C1	5.4
C2	1.27

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